Silicon P-Channel MOS FET

# HITACHI

November 1996

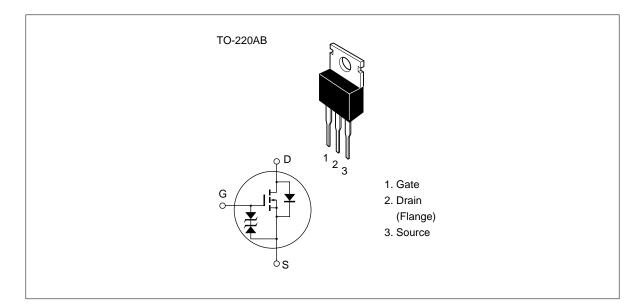
#### Application

High speed power switching

#### Features

- Low on-resistance
- High speed switching
- Low drive current
- 4 V gate drive device
  - Can be driven from 5 V source
- Suitable for motor drive, DC-DC converter, power switch and solenoid drive

#### Outline



#### **Absolute Maximum Ratings** (Ta = 25°C)

| Symbol           | Ratings   | Unit  |  |
|------------------|---|---|--|
| V <sub>DSS</sub> | -60   | V   |  |
| V <sub>GSS</sub> | ±20   | V   |  |
| I <sub>D</sub>   | -10   | A   |  |
| I *1<br>D(pulse) | -40   | A   |  |
| I <sub>DR</sub>  | -10   | A   |  |
| Pch*2            | 40  | W   |  |
| Tch              | 150   | °C  |  |
| Tstg             | -55 to +150   | °C  |  |
|                  | $V_{DSS}$ $V_{GSS}$ $I_D$ $I_{D(pulse)}^{*1}$ $I_{DR}$ $Pch^{*2}$ $Tch$ | V         -60           V $\pm 20$ I $-10$ I $-40$ I $-10$ Pch*2         40           Tch         150 |  |

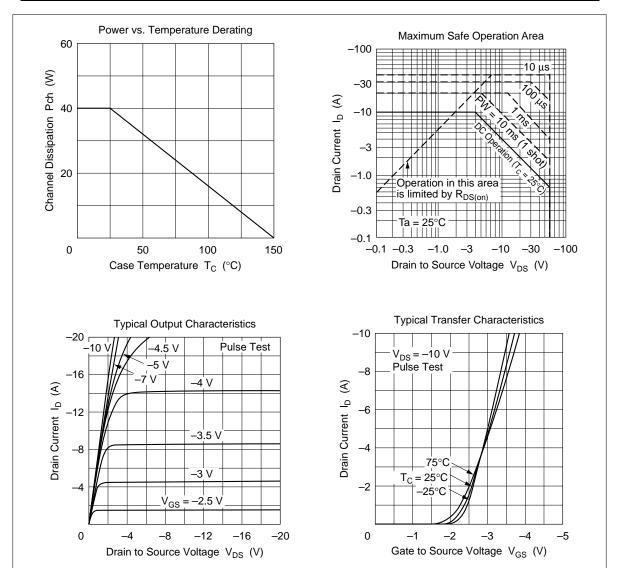
Notes 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

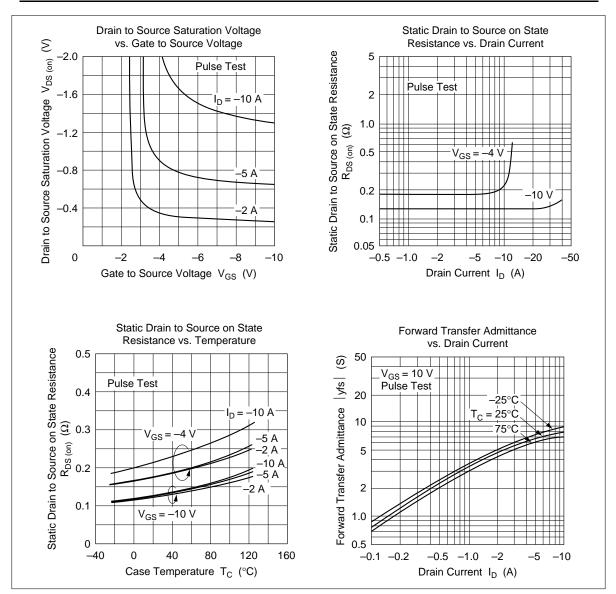
2. Value at T<sub>c</sub> =  $25^{\circ}$ C

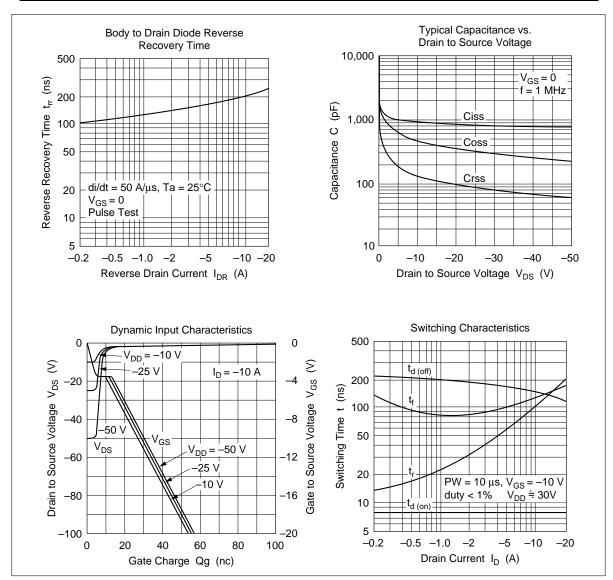
#### **Electrical Characteristics** (Ta = 25°C)

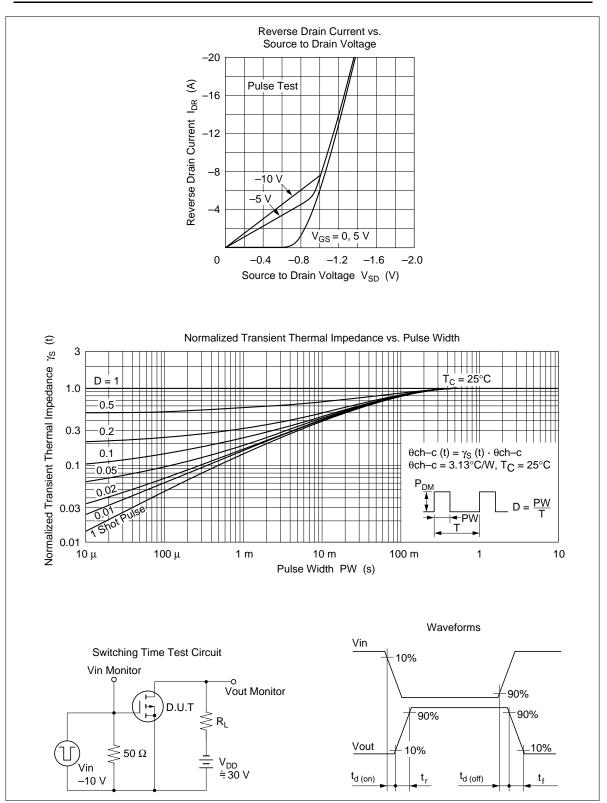
| Symbol                      | Min   | Тур   | Max  | Unit   | Test conditions  |
|-----------------------------|---|---|--|--|--|
| $V_{(\text{BR})\text{DSS}}$ | -60   | _   | _  | V  | $I_{\rm D} = -10$ mA, $V_{\rm GS} = 0$   |
| $V_{(BR)GSS}$               | ±20   | _   | _  | V  | $I_{g} = \pm 100 \ \mu A, \ V_{DS} = 0$  |
| I <sub>GSS</sub>            |   |   | ±10  | μA   | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$  |
| I <sub>DSS</sub>            |   |   | 250  | μA   | $V_{\rm DS} = -50$ V, $V_{\rm GS} = 0$   |
| V <sub>GS(off)</sub>        | -1.0  |   | -2.0   | V  | $I_{\rm D} = -1 \text{ mA}, V_{\rm DS} = -10 \text{ V}$                        |
| R <sub>DS(on)</sub>         |   | 0.13  | 0.18   | Ω  | $I_{\rm D} = -5$ A, $V_{\rm GS} = -10$ V <sup>*1</sup>                         |
|                             | _   | 0.18  | 0.25   |  | $I_{\rm D} = -5$ A, $V_{\rm GS} = -4$ V <sup>*1</sup>                          |
| y <sub>fs</sub>             | 4.0   | 6.5   |  | S  | $I_{\rm D} = -5$ A, $V_{\rm DS} = -10$ V <sup>*1</sup>                         |
| Ciss                        |   | 900   |  | pF   | $V_{DS} = -10 V, V_{GS} = 0,$  |
| Coss                        |   | 460   | _  | pF   | f = 1 MHz  |
| Crss                        | _   | 130   | —  | pF   | _  |
| t <sub>d(on)</sub>          |   | 8   |  | ns   | $I_{\rm D} = -5$ A, $V_{\rm GS} = -10$ V,                                      |
| t,                          |   | 65  |  | ns   | $R_{L} = 6 \Omega$   |
| t <sub>d(off)</sub>         |   | 170   |  | ns   |  |
| t <sub>f</sub>              |   | 105   | _  | ns   |  |
| $V_{\text{DF}}$             | _   | -1.1  |  | V  | $I_{F} = -10 \text{ A}, V_{GS} = 0$  |
| t <sub>rr</sub>             | _   | 200   | _  | ns   | $I_{F} = -10 \text{ A}, V_{GS} = 0,$<br>$di_{F}/dt = 50 \text{ A}/\mu\text{s}$ |
|                             | $V_{(BR)DSS}$ $V_{(BR)GSS}$ $I_{GSS}$ $I_{DSS}$ $V_{GS(off)}$ $R_{DS(on)}$ $Iy_{fs} $ $Cisss$ $Crss$ $Crss$ $t_{d(on)}$ $t_{r}$ $t_{d(off)}$ $t_{f}$ $V_{DF}$ | $\begin{array}{c} V_{(BR)DSS} & -60 \\ \\ V_{(BR)GSS} & \pm 20 \\ \\ I_{GSS} & \\ I_{DSS} & \\ \\ V_{GS(off)} & -1.0 \\ \\ R_{DS(on)} & \\ \\ \hline \\ V_{GS(off)} & -1.0 \\ \\ \hline \\ R_{DS(on)} & \\ \\ \hline \\ V_{I}f_{I} & 4.0 \\ \\ \hline \\ Ciss & \\ \hline \\ Ciss & \\ \hline \\ Coss & \\ \hline \\ Coss & \\ \hline \\ Crss & \\ \hline \\$ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $\begin{array}{c c c c c c c c } V_{(BR)DSS} & -60 & - & - \\ \hline V_{(BR)GSS} & \pm 20 & - & - \\ \hline I_{GSS} & - & - & \pm 10 \\ \hline I_{DSS} & - & - & 250 \\ \hline V_{GS(off)} & -1.0 & - & -2.0 \\ \hline R_{DS(on)} & - & 0.13 & 0.18 \\ \hline - & 0.13 & 0.18 \\ \hline - & 0.18 & 0.25 \\ \hline Iy_{fs} & 4.0 & 6.5 & - \\ \hline Ciss & - & 900 & - \\ \hline Coss & - & 460 & - \\ \hline Crss & - & 130 & - \\ \hline Crss & - & 130 & - \\ \hline t_{d(off)} & - & 8 & - \\ \hline t_{f} & - & 105 & - \\ \hline V_{DF} & - & -1.1 & - \\ \end{array}$ | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$                          |

Note 1. Pulse test









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